

Features

- Low power consumption:0.3uA (Typ.)
- Standby Mode: 0.01uA
- Low voltage drop: 180mV@100mA@VOUT=3.3V(Typ.)
- High Output Current: ≥400mA
- Low temperature coefficient
- Integrated Short-Circuit Protection
- Over-Temperature Protection

Applications

- Battery-powered equipment
- Communication equipment
- Mobile phones

General Description

Order Information HE207312345

The HE2073 series are highly accurate, low noise, CMOS LDO Voltage Regulators. Offering low output noise, high ripple rejection ratio, low dropout and very fast turn-on times, the HE9073 series is ideal for today's cutting edge mobile phone. Internally the HE9073 includes a reference voltage source, error amplifiers, driver transistors, current limiters and phase compensators.

The output voltage is set by current trimming. Voltages are selectable in 100mV steps within a range of 1.2V to 5.0V.

The HE2073 series is also fully compatible with

- High input voltage (up to 6V)
- Output voltage accuracy: tolerance ±2%
- Build-in Enable/Output Current Limit circuit
- SOT23-5、SOT23-3、SOT89-3L、 DFN1x1-4L package
- PSRR=60dB@1KHz
- Support Fixed Output Voltage: 1.2v/1.5v/1.8v/2.5v/2.8v/3.0v/3.3v
- Portable games
- Cameras, Video cameras
- Reference voltage sources

low ESR ceramic capacitors, reducing cost and improving output stability. This high level of output stability is maintained even during frequent load fluctuations, due to the excellent transient response performance and high PSRR achieved across a broad range of frequencies. The CE function allows the output of regulator to be turned off, resulting in greatly reduced power consumption.

Designator	Symbol	Description
1	А	Standard
23	Integer	Output Voltage(1.2~5.0V)
	D4	Package:DFN1x1-4L
	P Package:SOT89	
(4)	М	Package:SOT23-3
	M5	Package:SOT23-5
5	R	RoHS / Pb Free
	G	Halogen Free

Note:"23" stands for output voltages. Other voltages can be specially customized



Package and Pin assignment



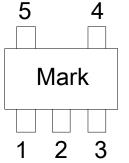
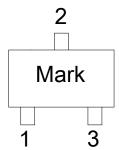


Table1: HE2073AXXM5R series (SOT23-5 PKG)

PIN NUMBER	SYMBOL	FUNCTION
1	V _{IN}	Power Input Pin
2	GND	Ground
3	CE	Chip Enable Pin
4	NC	No Connection
5	V _{OUT}	Output Pin

SOT23-3 (Top View)



SOT89-3 (Top View)

Mark



PIN NUMBER	SYMBOL	FUNCTION
1	GND	Ground
2	V _{IN}	Power Input Pin
3	V _{OUT}	Output Pin

Table3 HE2073AXXPR series (SOT89-3 PKG)

PIN NO.	PIN NAME	FUNCTION		
1	GND	GND pin		
2	VIN	Input voltage pin		
3	VOUT	Output voltage pin		

Table4 HE2073AXXD4R series (DFN1*1-4LPKG)

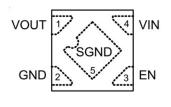
PIN NUMBER	SYMBOL	FUNCTION
1	V _{OUT}	Output Pin
2	GND	Ground
3	CE	Chip Enable Pin
4	V _{IN}	Power Input Pin
5	SGND	Substrate of Chip. Leave floating or tie to GND

DFN1x1-4L (Top View)

2

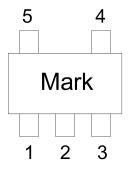
1

3





Marking Description



1 product code: 4

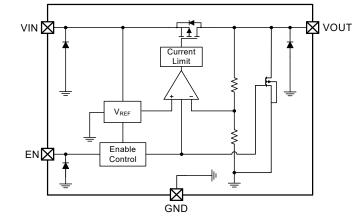
2 output voltage code:

Symbol	Voltage(V)	Symbol	Voltage(V)	Symbol	Voltage(V)	Symbol	Voltage(V)
а	0.9	А	3.5	n	2.2	Ν	4.8
b	1.0	В	3.6	0	2.3	0	4.9
С	1.1	С	3.7	Р	2.4	Р	5.0
d	1.2	D	3.8	q	2.5	Q	5.1
е	1.3	E	3.9	r	2.6	R	5.2
f	1.4	F	4.0	S	2.7	S	5.3
g	1.5	G	4.1	t	2.8	Т	5.4
h	1.6	Н	4.2	u	2.9	U	5.5
i	1.7	I	4.3	V	3.0	V	5.6
j	1.8	J	4.4	W	3.1	W	5.7
k	1.9	K	4.5	Х	3.2	Х	5.8
	2.0	L	4.6	у	3.3	Y	5.9
m	2.1	М	4.7	Z	3.4	Z	6.0

(3)(4): The last two of them are based on the time of this product which is the first time into production, the third is the year of this product first time into production, such as expressed in "1" in 2021, in "2" in 2022 and the forth is the mouth of this product first time into production, it can be in $1 \sim 9$, which is expressed in "0" in October, in November with an "A", in December with "B"; . For example: 4y16 represents HE2073A33M5R product is first put into production in June in 2021.



Block Diagram



Absolute Maximum Ratings

Supply Voltage-0.3V to 8V Operating Temperature-40 $^\circ\!\mathrm{C}$ to 85 $^\circ\!\mathrm{C}$

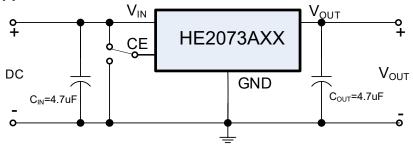
Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Symbol	Parameter	Package	Max.	Unit
	Thermal Resistance (Junction to	SOT23-3	500	°C/W
θ _{JA}	Ambient) (Assume no ambient	SOT23-5	500	°C/W
	airflow, no heat sink)	SOT89-3	200	°C/W
		DFN1x1-4L	500	°C/W
		SOT23-3	0.20	W
PD	Power Dissipation	SOT23-5	0.20	W
		SOT89-3	0.50	W
		DFN1x1-4L	0.20	W

Thermal Information

Note: P_D is measured at Ta= $25^\circ\!\mathbb{C}$

Typical Application Circuit





Electrical Characteristics

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
V_{IN}	Input Voltage		2		6	V
I _Q	Quiescent Current	V _{IN} > V _{OUT} ,EN=V _{IN} No load		0.3	0.7	μΑ
Vout	Output Voltage	I _{OUT} =1mA	-2.0		+2.0	%
I_{SD}	Shutdown Ground Current	V _{EN} =0V			0.1	μΑ
I _{LEAK}	V _{OUT} Shutdown Leakage Current	$V_{OUT} = 0V$	_		0.1	μΑ
I _{OUT_MAX}	Output Current	V_{IN} - V_{OUT} =0.5V	_	400		mA
V		$I_{OUT} = 100 \text{mA}$ $V_{OUT} = 3.3 \text{V}$	_	180	200	mV
V _{DROP}	Dropout Voltage ⁽¹⁾	I _{OUT} =200mA V _{OUT} =3.3V	_	400	450	mV
ΔLOAD	Load Regulation	V _{IN} =V _{OUT} +1V 1mA≤I _{OUT} ≤300mA	_	20	30	mV
ΔLINE	Line Regulation	$I_{OUT}=1mA,$ $V_{OUTNOM}+0.5V\leq V_{IN}\leq 7V$	_	0.1	0.15	%/V
I _{LIMIT}	Current Limit	$V_{IN} = 5V$		400		mA
DCDD	Derror Seconder Deitsteinen Detie	I _{OUT} =100mA f=10KHz		52		dB
PSRR	Power Supply Rejection Ratio	I _{OUT} =100mA f=1KHz		60		dB
Ishort	Short /Start Load Current	RL=1Ω		50		mA
V_{IH}	EN Threshold Voltage,Logic-High	V _{IN} =5.0V, I _{OUT} =1mA	1.2		_	V
V_{IL}	EN Threshold Voltage,Logic-Low	V _{IN} =5.0V			0.4	V
e _{NO}	Output Noise Voltage	10Hz to 100kHz C _{OUT} =1µF	_	100		μ ^V RMS
T_{SD}	Thermal Shutdown Temperature			160		°C
ΔT_{SD}	Thermal Shutdown Hysteresis			20		°C

 $(At T_{A=}25^{\circ}C, C_{IN}=1uF, V_{IN}=V_{OUT}+1.0V, V_{OUT}=3.3V, C_{OUT}=1\mu F, unless otherwise noted)$

Note: (1) Dropout Voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value.



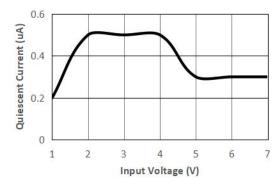
HE2073 0.3uA IQ Series High Speed Low Noise LDO

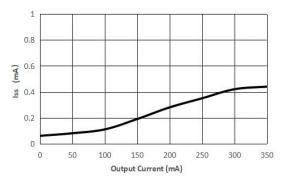
Typical Performance Characteristics

 $C_{\text{IN}}{=}1uF,\,C_{\text{OUT}}{=}1uF,\,V_{\text{IN}}{=}4.5V,\,V_{\text{OUT}}{=}3.3V\,\,,\text{SOT23-5},\text{T}_{\text{A}}{=}25^{\circ}\text{C}$

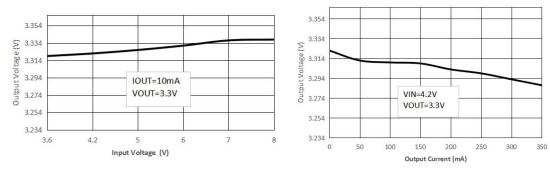
(Unless specified otherwise.Package:SOT23-5L)

(1) Quiescent current vs Input voltage

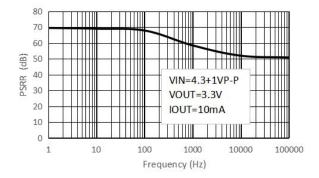




(2) Output Voltage vs Input voltage

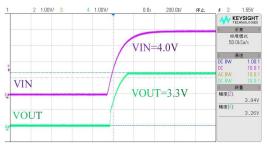


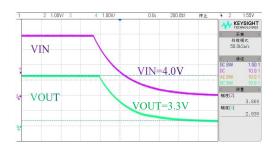






Power ON / OFF





EN ON/OFF

1 2 1.00V/ 3 2.00V	VIN=4.0V	
EN	EN=4.0V	DC BW 1.00: DC 10.0: DC 10.0:
22	VOUT=3.3V	0C BW 10 0: 一 初夏 最大电平(2): 4.08V 最大电平(3):
VOUT		4.18V 最大电平[4]: 3.42V

1 2 1.00V/ 3 2.	00V/ 4 1.00V/	0.0s	500.0%/	停止	t 4	1.76V
VIN	Į.	VIN=4	V0		₩ *	ECHNOLOGIES
Y 11 Y		,				采奥
						程模式 DMSa/s
EN					-	
LIN						通道
		EN=4	1.0V		DC BW	1.00:1
*					DC	10.0:
	-				DC BW	10.0
VOUT	-				最大电子	湖曼 : #[2]:
1001					DEC / TEL	4.081
	1				最大电1	
		VOUT	=3.3V		最大电4	4.100
					mc A HE H	3.30V

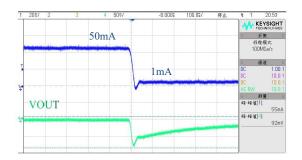
Line Transient

1	2 2.00V/ 3	4 100/	0.0s	1.000s/	停止	 <i>∓</i> 2	4.85V
				(4) = 13.50mV		••• т	EYSIGHT
			6V			标	采集 程模式
V	'IN	4.2V				1	OkSa/s
						DC	通道 1.00:
						DC DC	10.0 10.0
	OUT					AC BW	10.0 光标
	OUT					ΔX: +10.00	000000000
						1/ΔX:	+100.00mH
	diff which it will	an an the black		den har her sid	Halimitet	ΔY(2):	+3.53750
							10.00700

2 2.00V/ 3	4 100/	0.0s 1.000s/	停止	¥ 2 4.85V
	Ť			KEYSIGHT TECHNOLOGIES
VIN	6V			采集
· II ·	T			标准模式 10.0kSa/s
		4.2V		
				通道
				DC 1.00: DC 10.0:
				DC 10.0.
				AC BW 10.0.
VOUT				光桥 ΔX:
1001				+10.00000000000
				1/ΔX: +100.00mH
		AND THE REAL PROPERTY.		ΔY(2):
				+3.53750

Load Transient

20%/ 2	3 4	500/	-8.000%	100.0%/	停止	-f		4.0x
		-	50mA		turn la mataja		TECHN 采集 标准模 100MSa	ologie 式
IOUT	ln	nA				DC DC DC	通道	1.00 10.0 10.0
VOUT							BW 秋量 経催(1) 経催(4)	10.0 47n 66n





HE2073 0.3uA IQ Series High Speed Low Noise LDO

Operational Explanation

<Output Voltage Control>

The P-channel MOSFET is connected to the Vout pin, driven by the subsequent output signal. The output voltage at the Vout pin is controlled and stabilized by a system of negative feedback. The IC's internal circuitry can shut-down by the CE pin's signal

<Low ESR Capacitors>

With the HE2073 series, a stable output voltage is achievable even if used with low ESR capacitors as a phase compensation circuit is built-in. In order to ensure the effectiveness of the phase compensation, we suggest that an output capacitor (CL) is connected as close as possible to the output pin (VouT) and the GND pin. Please use an output capacitor with a capacitance value of at least 10uF. Also, please connect an input capacitor (CIN) of 10uF between the VIN pin and the GND pin in order to ensure a stable power input. Stable phase compensation may not be ensured if the capacitor runs out capacitance when depending on bias and temperature. In case the capacitor depends on the bias and temperature, please make sure the capacitor can ensure the actual capacitance.

<CE Pin>

The IC's internal circuitry can be shutdown via the signal from the CE pin with the HE9073 series. The operational logic of the IC's CE pin is selectable (please refer to the selection guide). Although the CE pin is equal to an inverter input with CMOS hysteresis, with either the pull-up or pull-down options, the CE pin input current will increase when the IC is in operation. We suggest that you use this IC with either a VIN voltage or a VSs voltage input at the CE pin. If this IC is used with the correct specifications for the CE pin, the operational logic is fixed and the IC will operate normally. However, supply current may increase as a result of through current in the IC's internal circuitry.

Notes on Use

1. Please use this IC within the stated absolute maximum ratings. The IC is liable to malfunction should the ratings be exceeded.

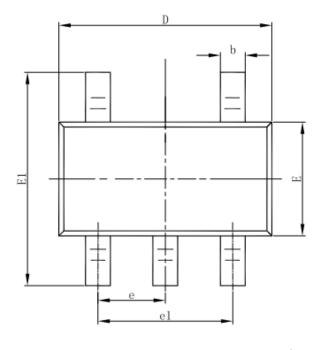
2. Where wiring impedance is high, operations may become unstable due to noise and/or phase lag depending on output current. Please keep the resistance low between VIN and Vss wiring in particular.

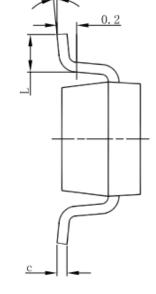
3. Please wire the input capacitor (CIN) and the output capacitor (CL) as close to the IC as possible.



Packaging Information

SOT23-5 Outline Dimensions



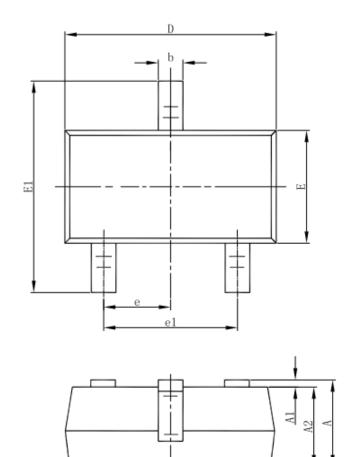


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			42 V
	—	7	
			↓ ↓

Sumbal	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(0.950(BSC) 0.037(BSC)		BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	<mark>0</mark> °	8°



3-pin SOT23-3 Outline Dimensions

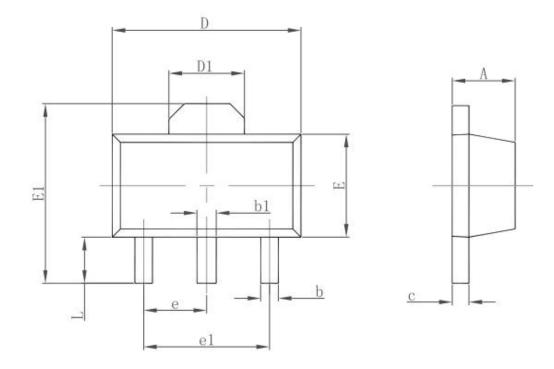


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Ц		
	+	+-+
c		لر

Symbol	Dimensions Ir	n Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950	0.950(BSC) 0.037(BSC)		BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°



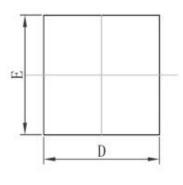
Package Information 3-pin SOT89 Outline Dimensions



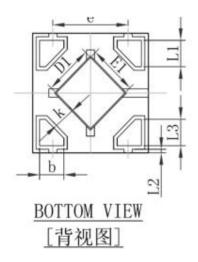
Cumb al	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500 TYP.		0.060 TYP.	
e1	3.000	TYP.	0.118	3 TYP.
L	0.900	1.200	0.035	0.047

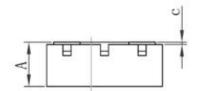


DFN1×1-4 Outline Dimensions



<u>TOP VIEW</u> [顶视图]





Sumbal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A	0.335	0.405	0.013	0.016
D	0.950	1.050	0.037	0.041
E	0.950	1.050	0.037	0.041
D1	0.370	0.470	0.015	0.019
E1	0.370	0.470	0.015	0.019
k	0.17MIN.		0.007MIN.	
b	0.160	0.260	0.006	0.010
С	0.010	0.090	0.000	0.004
е	0.600	0.700	0.024	0.028
L1	0.185	0.255	0.007	0.010
L2	0.030 REF.		0.001	REF.
L3	0.185	0.255	0.007	0.010

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